

## PHASE CONTROL THYRISTORS

## Hockey Puk Version

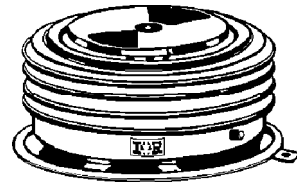
### Features

- Center amplifying gate
- Metal case with ceramic insulator
- International standard case A-24 (K-PUK)
- High profile hockey-puk

### Typical Applications

- DC motor controls
- Controlled DC power supplies
- AC controllers

1745A



case style A-24 (K-PUK)

### Major Ratings and Characteristics

Parameters	ST1230C..K	Units
$I_{T(AV)}$	1745	A
	@ $T_{hs}$	55 °C
$I_{T(RMS)}$	3200	A
	@ $T_{hs}$	25 °C
$I_{TSM}$	@ 50Hz	33500 A
	@ 60Hz	35100 A
$I^2t$	@ 50Hz	5615 KA <sup>2</sup> s
	@ 60Hz	5126 KA <sup>2</sup> s
$V_{DRM}/V_{RRM}$	800 to 1600	V
$t_q$ typical	200	μs
$T_J$	- 40 to 125	°C

**ELECTRICAL SPECIFICATIONS**

Voltage Ratings

Type number	Voltage Code	$V_{DRM}/V_{RRM}$ , max. repetitive peak and off-state voltage V	$V_{RSM}$ , maximum non-repetitive peak voltage V	$I_{DRM}/I_{RRM}$ max. @ $T_J = T_J$ max mA
ST1230C..K	08	800	900	100
	12	1200	1300	
	14	1400	1500	
	16	1600	1700	

On-state Conduction

Parameter	ST1230C..K	Units	Conditions	
$I_{T(AV)}$ Max. average on-state current @ Heatsink temperature	1745 (710)	A	180° conduction, half sine wave double side (single side) cooled	
	55 (85)	°C		
$I_{T(RMS)}$ Max. RMS on-state current	3200	A	DC @ 25°C heatsink temperature double side cooled	
$I_{TSM}$ Max. peak, one-cycle non-repetitive surge current	33500		t = 10ms	No voltage
	35100		t = 8.3ms	reapplied
	28200		t = 10ms	100% $V_{RRM}$
	29500	t = 8.3ms	reapplied	
$I^2t$ Maximum $I^2t$ for fusing	5615	KA <sup>2</sup> s	t = 10ms	Sinusoidal half wave, Initial $T_J = T_J$ max.
	5126		t = 8.3ms	
	3971		t = 10ms	
	3625		t = 8.3ms	
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	56150	KA <sup>2</sup> √s	t = 0.1 to 10ms, no voltage reapplied	
$V_{T(TO)1}$ Low level value of threshold voltage	0.93	V	(16.7% x $\pi$ x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$ ), $T_J = T_J$ max.	
$V_{T(TO)2}$ High level value of threshold voltage	1.02		( $I > \pi$ x $I_{T(AV)}$ ), $T_J = T_J$ max.	
$r_{t1}$ Low level value of on-state slope resistance	0.17	mΩ	(16.7% x $\pi$ x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$ ), $T_J = T_J$ max.	
$r_{t2}$ High level value of on-state slope resistance	0.16		( $I > \pi$ x $I_{T(AV)}$ ), $T_J = T_J$ max.	
$V_{TM}$ Max. on-state voltage	1.62	V	$I_{pk} = 4000A$ , $T_J = T_J$ max, $t_p = 10ms$ sine pulse	
$I_H$ Maximum holding current	600	mA	$T_J = 25^\circ C$ , anode supply 12V resistive load	
$I_L$ Typical latching current	1000			

Switching

Parameter	ST1230C..K	Units	Conditions
di/dt Max. non-repetitive rate of rise of turned-on current	1000	A/ $\mu$ s	Gate drive 20V, 20 $\Omega$ , $t_r \leq 1\mu$ s $T_J = T_J$ max, anode voltage $\leq 80\%$ $V_{DRM}$
$t_d$ Typical delay time	1.9	$\mu$ s	Gate current 1A, $di_g/dt = 1A/\mu$ s $V_d = 0.67\%$ $V_{DRM}$ , $T_J = 25^\circ$ C
$t_q$ Typical turn-off time	200		$I_{TM} = 550A$ , $T_J = T_J$ max, $di/dt = 40A/\mu$ s, $V_R = 50V$ $dv/dt = 20V/\mu$ s, Gate 0V 100 $\Omega$ , $t_p = 500\mu$ s

Blocking

Parameter	ST1230C..K	Units	Conditions
dv/dt Maximum critical rate of rise of off-state voltage	500	V/ $\mu$ s	$T_J = T_J$ max. linear to 80% rated $V_{DRM}$
$I_{RRM}$ $I_{DRM}$ Max. peak reverse and off-state leakage current	100	mA	$T_J = T_J$ max, rated $V_{DRM}/V_{RRM}$ applied

Triggering

Parameter	ST1230C..K	Units	Conditions
$P_{GM}$ Maximum peak gate power	16	W	$T_J = T_J$ max, $t_p \leq 5$ ms
$P_{G(AV)}$ Maximum average gate power	3		$T_J = T_J$ max, $f = 50$ Hz, $d\% = 50$
$I_{GM}$ Max. peak positive gate current	3.0	A	$T_J = T_J$ max, $t_p \leq 5$ ms
$+V_{GM}$ Maximum peak positive gate voltage	20	V	$T_J = T_J$ max, $t_p \leq 5$ ms
$-V_{GM}$ Maximum peak negative gate voltage	5.0		
$I_{GT}$ DC gate current required to trigger	TYP.	MAX.	$T_J = -40^\circ$ C $T_J = 25^\circ$ C $T_J = 125^\circ$ C Max. required gate trigger/ current/ voltage are the lowest value which will trigger all units 12V anode-to-cathode applied
	200	-	
	100	200	
$V_{GT}$ DC gate voltage required to trigger	1.4	-	$T_J = -40^\circ$ C $T_J = 25^\circ$ C $T_J = 125^\circ$ C
	1.1	3.0	
	0.9	-	
$I_{GD}$ DC gate current not to trigger	10	mA	$T_J = T_J$ max Max. gate current/voltage not to trigger is the max. value which will not trigger any unit with rated $V_{DRM}$ anode-to-cathode applied
$V_{GD}$ DC gate voltage not to trigger	0.25	V	

# ST1230C..K Series

## Thermal and Mechanical Specification

Parameter	ST1230C..K	Units	Conditions
T <sub>J</sub> Max. operating temperature range	-40 to 125	°C	
T <sub>stg</sub> Max. storage temperature range	-40 to 150		
R <sub>thJ-hs</sub> Max. thermal resistance, junction to heatsink	0.042	K/W	DC operation single side cooled
	0.021		DC operation double side cooled
R <sub>thC-hs</sub> Max. thermal resistance, case to heatsink	0.006	K/W	DC operation single side cooled
	0.003		DC operation double side cooled
F Mounting force, ± 10%	24500	N	
	(2500)	(Kg)	
wt Approximate weight	425	g	
Case style	A-24 (K-PUK)		See Outline Table

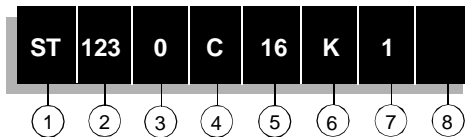
## ΔR<sub>thJ-hs</sub> Conduction

(The following table shows the increment of thermal resistance R<sub>thJ-hs</sub> when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction		Rectangular conduction		Units	Conditions
	Single Side	Double Side	Single Side	Double Side		
180°	0.003	0.003	0.002	0.002	K/W	T <sub>J</sub> = T <sub>J</sub> max.
120°	0.004	0.004	0.004	0.004		
90°	0.005	0.005	0.005	0.005		
60°	0.007	0.007	0.007	0.007		
30°	0.012	0.012	0.012	0.012		

## Ordering Information Table

### Device Code



- 1** - Thyristor
- 2** - Essential part number
- 3** - 0 = Converter grade
- 4** - C = Ceramic Puk
- 5** - Voltage code: Code x 100 = V<sub>RRM</sub> (See Voltage Rating Table)
- 6** - K = Puk Case A-24 (K-PUK)
- 7** - 0 = Eyelet terminals (Gate and Auxiliary Cathode Unsoldered Leads)  
 1 = Fast-on terminals (Gate and Auxiliary Cathode Unsoldered Leads)  
 2 = Eyelet terminals (Gate and Auxiliary Cathode Soldered Leads)  
 3 = Fast-on terminals (Gate and Auxiliary Cathode Soldered Leads)
- 8** - Critical dv/dt: None = 500V/μsec (Standard selection)  
 L = 1000V/μsec (Special selection)

Outline Table

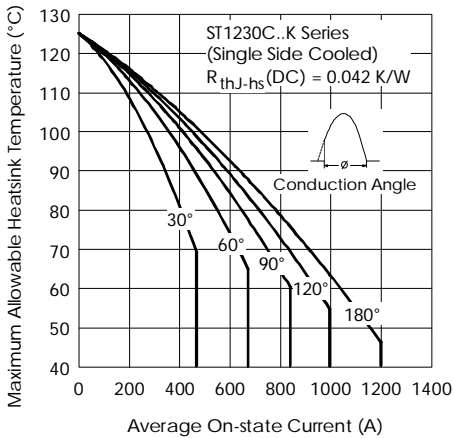
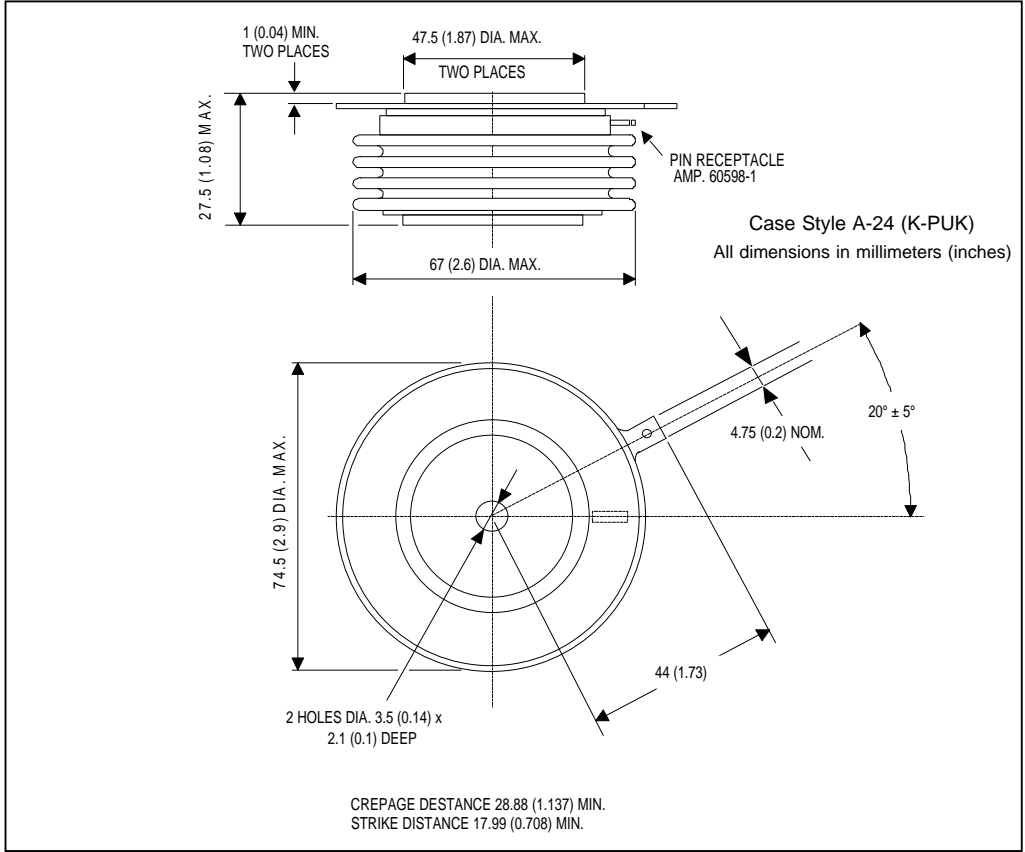


Fig. 1 - Current Ratings Characteristics

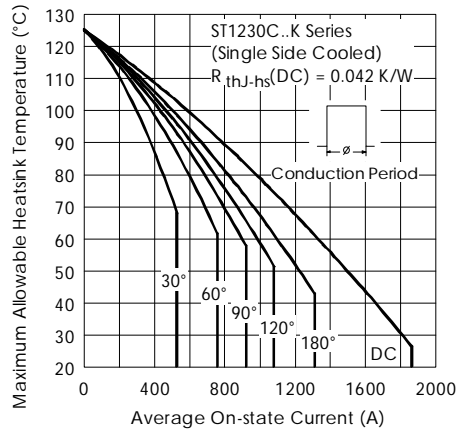


Fig. 2 - Current Ratings Characteristics

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- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
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- Работу по проектам и поставку образцов.
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- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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